MASSACHUSETTS INSTITUTE OF TECHNOLOGY

5.61 Physical Chemistry I Fall, 2017

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Lecture 25: Molecular Orbital Theory of Diatomic Molecules. II

In 5.111/5.112 we use orbital energies and *shielding* arguments to rationalize the Periodic Table. All properties, all atoms: IP, Electronegativity, size (via IP and modified Rydberg formula).

My personal vision has been to extend the periodicity of electronic properties from atoms to molecules. This lecture and a significant part of Exam III is constructed around that vision.

This lecture is intended to enable you to intuit the properties of H_2 , AH, A₂, and AB diatomic molecules. Larger molecules would follow.

Toy Models — naive but SMART approximations

Semi-Empirical calculations — to calibrate the Toy Model based on *atomic energy levels*, *atomic sizes*, and *qualitative lessons learned from* the H_2^+ LCAO-MO model.

Orbitals: Pictures, Names, Bonding/Anti-bonding Properties



bonding is due to constructive interference that arises from overlap, S, in the region between the 2 nuclei



Bond strength is roughly proportional to overlap

$$S_{n\ell\lambda}(R) = \int n\ell\lambda_A(\vec{r}_A; R) n\ell\lambda_B(\vec{r}_B; R) d\tau.$$

The molecular orbital is bonding if 2 atomic orbitals in the overlap region have same phase, anti-bonding if they have opposite phase.

Body frame g, u inversion symmetry (g = gerade or even, u = ungerade or odd)

 * is extra notation (optional) for anti-bonding

What did we learn from H_2^+ ?



 $\sigma_g(1s)$ less bonding than $\sigma_u^{\star}(1s)$ is anti-bonding

IP (H₂⁺) $X^2\Sigma_g^+ \sim$ IP (H) plus bonding (D_e^e) stabilization due to one e^- in $\sigma_g(1s)$ Electronic Ground state in $\sigma_g(1s) X^2\Sigma_g^+$ is bound!

Excited state \mathbf{A}^2 Σ^+_u is repulsive

$$R_e(\mathrm{H}_2^+) < 2 \left< r \right>_{H \ 1s}$$

Minimal Basis Set Variational Calculation

(what is the Variational Theorem?)

$$2 \text{ AO's} \rightarrow 2 \text{ MO's}$$

minimize E_{avg}

determine ground state E(R) and R_e (equilibrium internuclear distance)

more variational functions would give more accurate values. Requires computer.

Trust our model for qualitative insights

Extrapolate from H_2^+ to H_2 . What happens to molecular properties if we add another e^-

- get R_e decrease by ~ 30%
- get ω_e increase by ~ 90% (vibrational frequency)
- get D_e^e (dissociation energy) increase by ~ 70%

concept of "bond". Go from 1/2 bond to full bond.

In chemistry we think of a bond as involving $2e^-$. Why not 1 or 3? You can put $2e^-$ into one orbital $(\alpha\beta - \beta\alpha)$ but not $3e^-$.

More on H_2^+

The $1s_A, 1s_B$ basis set gave (McQuarrie)

$$S(R) = e^{-R} \left(\underbrace{1+R+\frac{1}{3}R^2}_{H_{12}(R)} \right)$$
 at large R, S is driving force for bonding

$$H_{12}(R) = e^{-R} \left(\underbrace{\frac{1}{R} - \frac{1}{2} - \frac{1}{6}R - \frac{1}{6}R^2}_{H_{13}(R)} \right)$$
 at large R, S is driving force for bonding

$$\varepsilon(R) = -\frac{1}{2} + \underbrace{e^{-2R} \left(1 + \frac{1}{R}\right)}_{\text{bare H}^+ \text{ penetrates inside H atom. Sees repulsion by progressively less-shielded nucleus as R -decreases.$$

Everything is atom-like at large-R

Bonding begins as R decreases, initially $\propto S$

Bonding turns around and is cancelled by overlap repulsion at short R [at what R would you expect this to begin to be important?]

$$R < 2 \langle r \rangle_{n\ell}$$
 (z direction)

Short step from H_2^+ to H_2 to A_2

How many e^- ?

Feed e^- into lowest orbitals following "exclusion principle"

Configuration: list of occupied orbitals

Excited configurations too \rightarrow excited states

Configurations can give rise to several electronic states, as for $He(1s 2s) : {}^{1}S + {}^{3}S$

for H₂ $X^{1}\Sigma_{g}^{+}$ $\sigma_{g}(1s)^{2}$ bound $a^{3}\Sigma_{u}^{+}$ $\sigma_{g}(1s)\sigma_{u}^{\star}(1s)$ repulsive

There could also be σ_g , σ_u , π_g , π_u orbitals arising from 2s, 2p

These n = 2 orbitals are much less bonding/anti-bonding: WHY? orbital size, much smaller S at R_e of $X^1\Sigma_g^+$ ground electronic state

$H_2 \rightarrow AH$ (NH as example)



AO Energies (from Atomic Spectra) [Semi-Empirical]

 $\begin{array}{c|c} \underline{\text{IE}} \\ \text{H (1s)} & 13.6 \text{ eV} \\ \hline \text{H(2s, 2p)} & 3.4 \text{ eV} \\ \text{N(1s)} & > 100 \text{ eV} \\ \text{N(2s)} & \sim 18 \text{ eV} \\ \text{N(2p)} & \sim 12 \text{ eV} \\ \hline \text{NH } X^3 \Sigma_q^- & \sim 13.6 \text{ eV} \end{array} \text{ bonding}$

Total number of $e^- = 8$. Look at order of IE to guide the order in which orbitals are filled. $2e^-$ in N(1s), $2e^-$ in N(2s), $2e^-$ in H–N $1s\sigma - 2p\sigma$ strong covalent bond, $2e^-$ in Non-BONDING N($2p\pi$)

We have

atom-localized $\xrightarrow{\sigma^2 \sigma^2} \xrightarrow{\sigma^2} \pi^2 \qquad \pi^2 : {}^{3}\Sigma^{-}, {}^{1}\Delta, {}^{1}\Sigma^{+}$ electronic states bonding non-bonding

 $Predict IP(NH) = IP[N 2p] + D_e^e$

LCAO-MO for A_2

 $Li_2...F_2$

Always in textbooks

To begin — look up (from atomic spectra)

Atom A 2p,2s AO energies relative to A⁺

Now to build a PRIMITIVE LCAO-MO diagram.

This is intentionally naive because it requires addition of extra effects, based on some empirical observations on a few systems generalized to many systems.



Facts: 2s smaller than 2p because of higher Ionization Energy, hence smaller size. Overlap starts at smaller R. $\sigma_g(2p)$ more bound than $\pi_u(2p)$ overlap because p orbital is extended along z.

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See Fig. 11.4 in McQuarrie, Donald A. *Quantum Chemistry, 2nd Edition*. University Science Books, 2007. ISBN: 9781891389504.

 $\sigma_g(2{\rm s})$ and $\sigma_g(2{\rm p})$ have same σ_g symmetry so they can interact. Also true for

 $\sigma_u^{\star}(2s)$ and $\sigma_u^{\star}(2p)$.

Also π_u , π_g^* have no π orbital below — no upward shift due to repulsion from below. Why does $\sigma(2s) \sim \sigma(2p)$ interaction change as we go across period Li \rightarrow F? Atom ion-core shielding effects cause an increase in s, p energy gap.

$$----- \sigma_g(2\mathbf{p})$$



Repulsion shift from nominal pattern decreases $Li \rightarrow F$

 $\begin{array}{ll} \mbox{toward nominal} & \sigma_g < \pi_u & {\rm O,F} \\ \mbox{starts out} & \pi_u < \sigma_g & {\rm Li} \dots {\rm N} \\ \mbox{inverted} \end{array}$

Crude interpretive use of non-degenerate perturbation theory:

for A-A
$$\varepsilon_{n\ell\lambda_A}^{\circ} = \varepsilon_{n\ell\lambda_A}^{\circ}$$

 $V_{n\ell\lambda}^{AA} = \frac{1}{2}(n\ell\lambda^* - n\ell\lambda).$

R-dependent energy difference between anti-bonding and bonding orbital.

For A-B $\varepsilon_{n\ell\lambda_A}^{\circ} \neq \varepsilon_{n\ell\lambda_B}^{\circ}$. Use this $V_{n\ell\lambda}^{AA}$ to guess value of $V_{n\ell\lambda}^{AB}$

$$V_{n\ell\lambda}^{AB} = \int \psi_{n\ell\lambda_A}^{\circ} \mathbf{H}^{(1)} \psi_{n\ell\lambda_B}^{\circ} d\tau$$

Alternatively, could estimate $V^{AB}_{n\ell\lambda}$ from

$$\left[\left(V_{n\ell\lambda}^{AA}\right)\left(V_{n\ell\lambda}^{BB}\right)\right]^{1/2}$$

So from $\varepsilon_{n\ell\lambda^*} - \varepsilon_{n\ell\lambda} = 2V_{n\ell\lambda}^{AB}$ now we can use this semi-empirical value of $V_{n\ell\lambda}^{AB}$ to predict $V_{n\ell'\lambda'}^{AB}$ for some molecule guided by orbital size (orbital ionization energy) or S(R) overlap or for neighboring AB molecules where

$$\begin{aligned} \varepsilon_{n\ell\lambda_A}^{(0)} \neq \varepsilon_{n\ell\lambda_B}^{(0)} \\ \begin{pmatrix} \varepsilon_{n\ell\lambda_A}^{(0)} & V \\ V & \varepsilon_{n\ell\lambda_B}^{(0)} \end{pmatrix} \end{aligned}$$

So we can explain, anticipate, and exploit predicted "anomalies".



Unequal sharing of orbitals from ${\cal A}$ vs. ${\cal B}$

Use non-degenerate perturbation theory to estimate:

• fractional A, B character in orbital

- polar bonding
- sign of polarity depends on number of e^-
- vs. equal sharing for A_2 molecules
- how does a molecule bind to a metal surface? positive end down, negative end down, lying down?

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